

Gate Driver IC for IGBTs and SiC MOSFETs

Gate Driver Evaluation Board for Inverter EV-GDIS16 User Guide

Introduction

This user guide describes the configuration and usage of the EV-GDIS16 evaluation board for Renesas's Gate Driver products in SOP-16 package.

The EV-GDIS16 board is designed for quick evaluation of Renesas Gate Drivers and is not intended to evaluate or guarantee all the characteristics of the Gate Driver products it is equipped with.



Target Device

Renesas Electronics Gate Driver series
RAJ293000 and other future products

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1. Getting Start

1.1 EV-GDIS and Interface board connection method and external view

Connect U9 on EV-GDIS to U10 on the interface board as shown in Figure 1 to connect EV-GDIS and interface board. Figure 2 shows the overall appearance of the connected EV-GDIS and interface board.

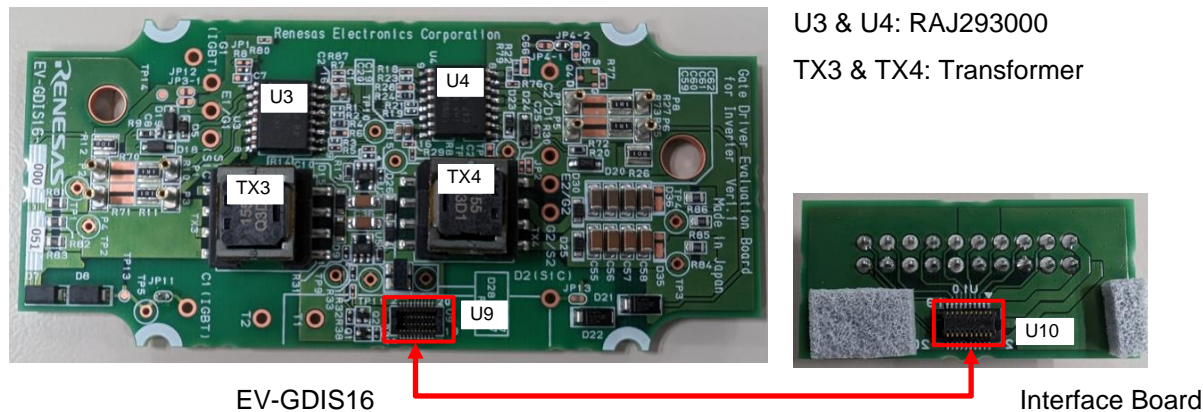


Figure 1. How to connect EV-GDIS16 and Interface board

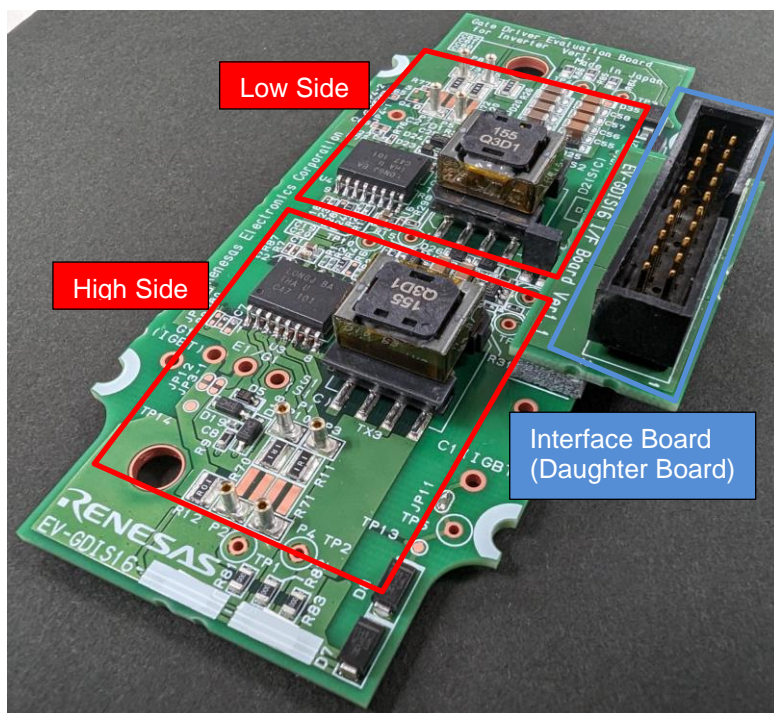


Figure 2. Overall appearance of board

1.2 How to switch IGBT/SiC modules

EV-GDIS supports IGBT and SiC modules. By default, EV-GDIS supports IGBT modules, which is realized by soldering the jumpers in red frame as shown in Figure 3.

To switch to SiC module, remove the jumpers in the red frame in Figure 3 and solder the jumpers in the yellow frame. Refer Chapter 7 for details.

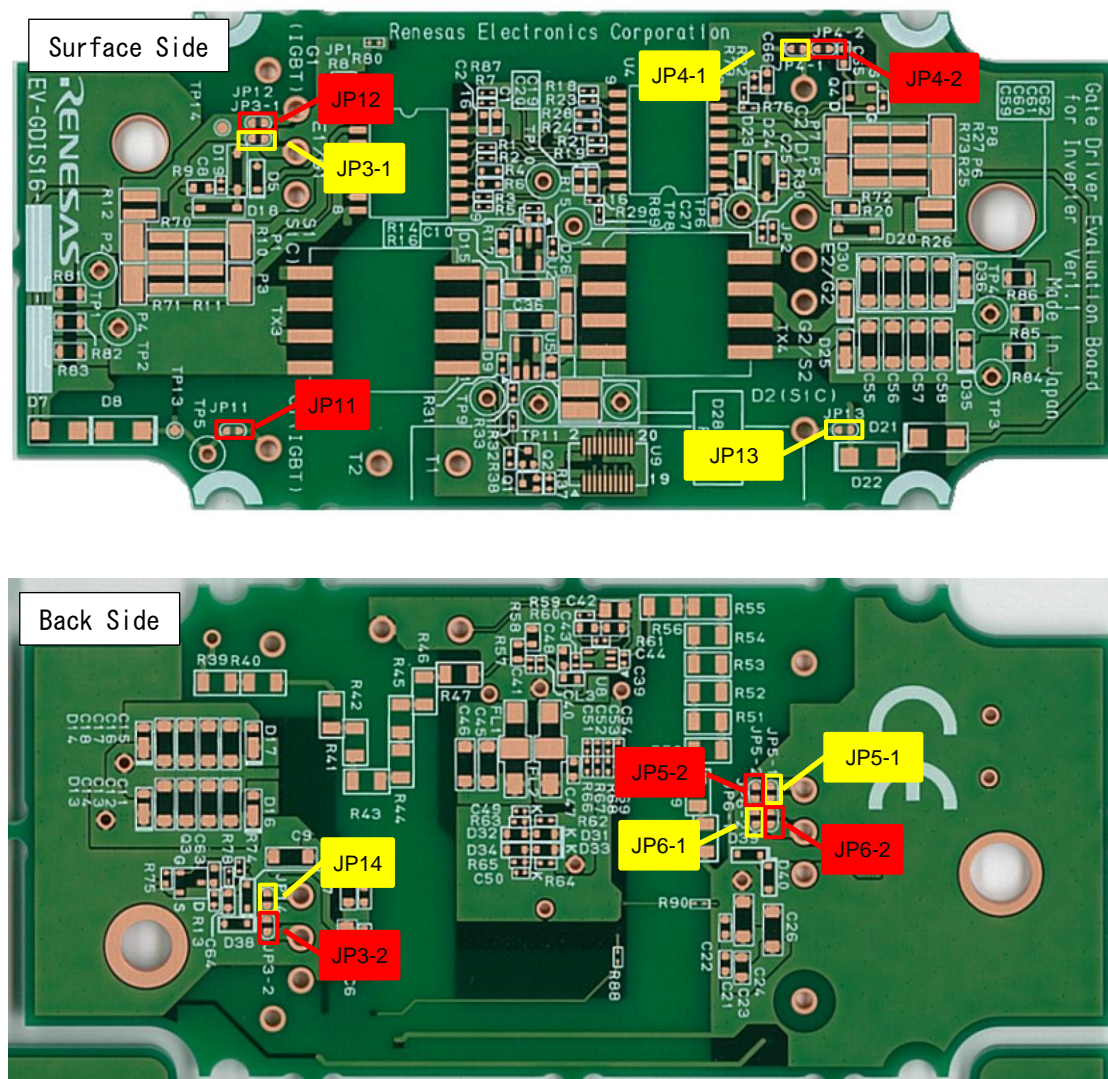


Figure 3. Jumper switching positions for IGBT and SiC

1.3 Simple operation method

Figure 4 shows a schematic diagram of a simple operation method of EV-GDIS. First, connect EV-GDIS and Interface board as shown in Figure 1. Apply voltage in the following order when connecting to the module and evaluating.

- ① Apply 12V to pin1 of I/F Board
- ② Apply 5V to pin2 of I/F Board
- ③ Apply a square wave of 0V-5V to each of the pin8 (UH_H) and pin4 (UL_H) of the I/F Board

Please set to prevent High side and Low side from being ON at the same time.

Refer Chapter 3 for pinout and connector details.

The output pin leading to the gate of the module is different when using the IGBT module and the SiC module. Figure 4 shows the position of the IGBT output pin with a red frame, and the position of the SiC output pin with a yellow frame.

When evaluating by connecting to a module, voltage is applied to the DESATpin internally and the board operates, but when evaluating the board alone,

DESATpin needs an externally applied power supply (eg. 1V) as indicated by dotted line in Figure 4.

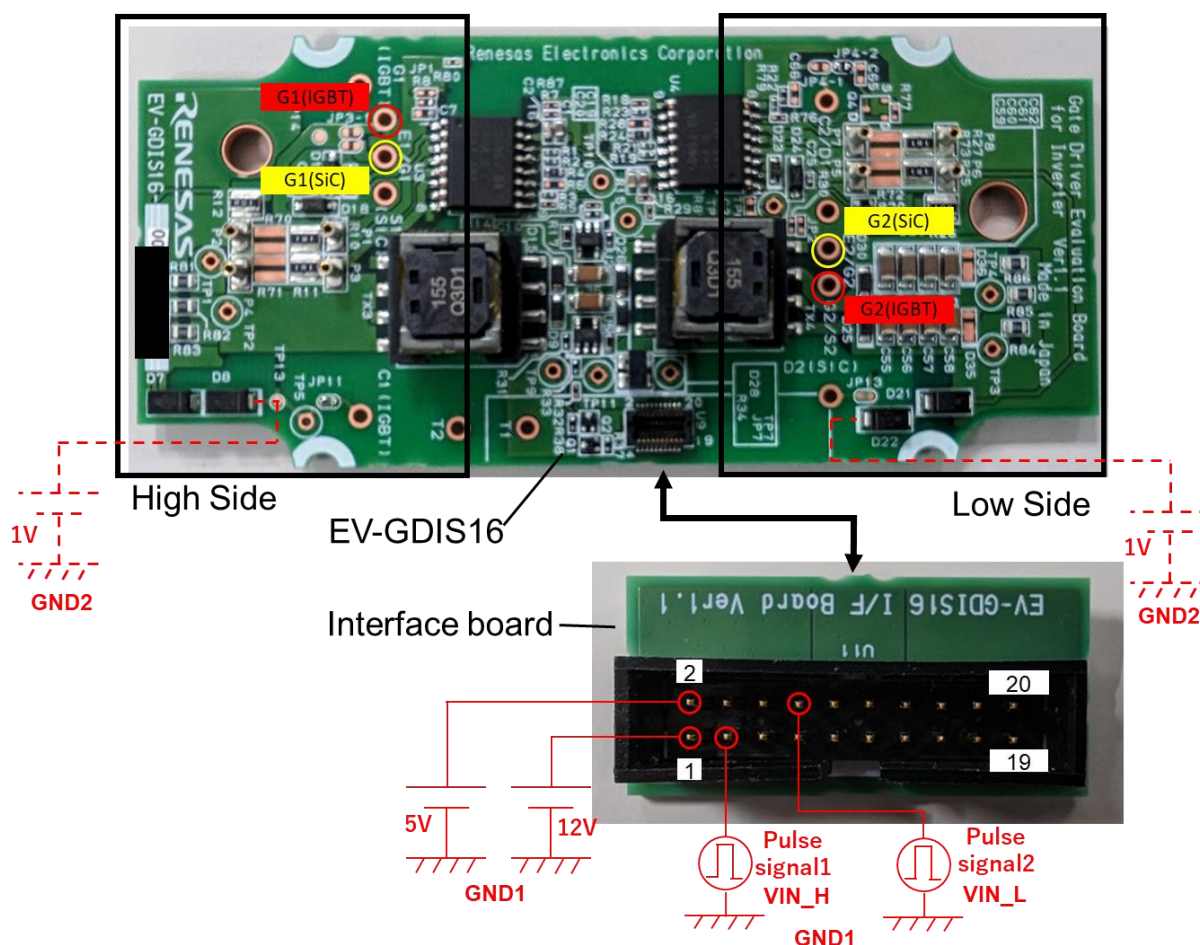


Figure 4. EV-GDIS Simple Operation Method

2. EV-GDIS16 Evaluation Board overview

EV-GDIS16 is a board for quick evaluation of Renesas' Gate Driver products in SOP-16 package. The boards are equipped with the necessary connectors and jumpers for evaluation, allowing customers to start evaluation early, before developing their own boards for target products. The Gate Driver products mounted on this evaluation board are working samples and the quality is not guaranteed.

The EV-GDIS16 board consists of a main board and an interface board, which has user-friendly pin-pitch connectors and components for double-pulse testing.

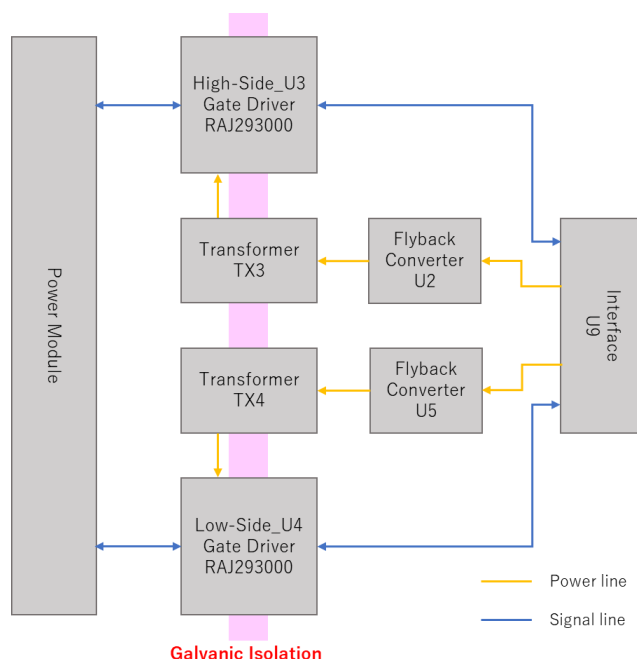
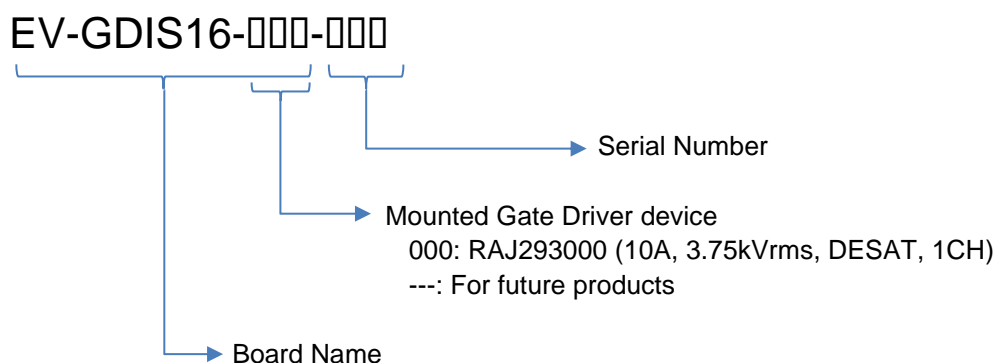


Figure 5. EV-GDIS16 block diagram

2.1 Board Name

The board name is marked on the board to identify the device it is equipped with.



3. PCB specification

The EV-GDIS16 uses an automotive grade PCB. The board size and number of layers are as below.

Table 1. PCB specification

| Parameter | Value |
|-----------------------|-------------------------|
| Board size | 104.5 mm x 47.0 mm |
| Thickness of PCB | 1.6 mm |
| Thickness of Cu layer | 20 µm |
| Cu layer numbers | 6 layer, 1-4-1 build-up |
| Board material | FR4 |

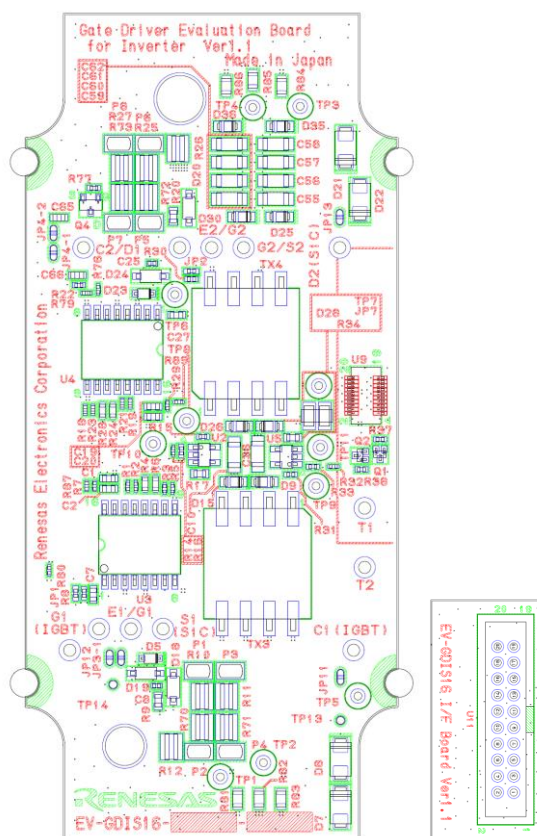


Figure 6. Layout of EV-GDIS16 (Main / Interface board)

4. Connectors

EV-GDIS16 is equipped with a connector and test pins to evaluate the on-board Gate Driver. Please refer to the following table for the description of each and precautions for use.

Table 2. Connectors

| Connector | Pin count | Function |
|-----------|-----------|--|
| U9 | 20 | U9 is a fine pitch connector mounted on EV-GDIS16. It is connected to U10 on the I/F Board. |
| U10 | 20 | U10 is a fine pitch connector mounted on I/F board. It is connected to U9 on the EV-GDIS16. |
| U11 | 20 | U11 is a connector on the I/F Board that allows signal input/output to/from the EV-GDIS16 Board. Please refer to Chapter 4 for U11 signal details. |
| C2/D1*1 | 1 | This is the terminal to be connected to C2 on the IGBT module or D1 on the SiC module. |
| G2/S2*1 | 1 | This is the terminal to be connected to G2 on the IGBT module or S2 on the SiC module. |
| E2/G2*1 | 1 | This is the terminal to be connected to E2 on the IGBT module or G2 on the SiC module. |
| D2(SiC) | 1 | This is the terminal to be connected to D2 on the SiC module. |
| S1(SiC) | 1 | This is the terminal to be connected to S1 on the SiC module. |
| E1/G1*1 | 1 | This is the terminal to be connected to E1 on the IGBT module or G1 on the SiC module. |
| G1(IGBT) | 1 | This is the terminal to be connected to G1 on the IGBT module. |
| C1(IGBT) | 1 | This is the terminal to be connected to C1 on the IGBT module. |
| T1 | 1 | The T1 terminal is connected to the T1 of the Integrated NTC temperature of the IGBT/SiC module. |
| T2 | 1 | The T2 terminal is connected to the T2 of the Integrated NTC temperature of the IGBT/SiC module. |

Note1: The signal numbering depends on where the board is mounted in the 6pack module.

8. Target Modules

The EV-GDIS16 evaluation board is designed to be combined with a general IGBT/SiC power module to evaluate the on-board Renesas Gate Driver IC. The EV-GDIS16 is designed to allow three boards to be mounted side-by-side on these target modules. These IGBT/SiC modules are subject to change in the future.

Table 5. Target Modules

| Module Type | Part Number | Description |
|-------------|----------------|--|
| IGBT | FS950R08A6P2B | HybridPACK Drive module with Trench/Fieldstop IGBT4 and Emitter Controlled 4 diode |
| SiC | FS03MR12A6MA1B | HybridPACK Drive module with CoolSiC Automotive MOSFET |

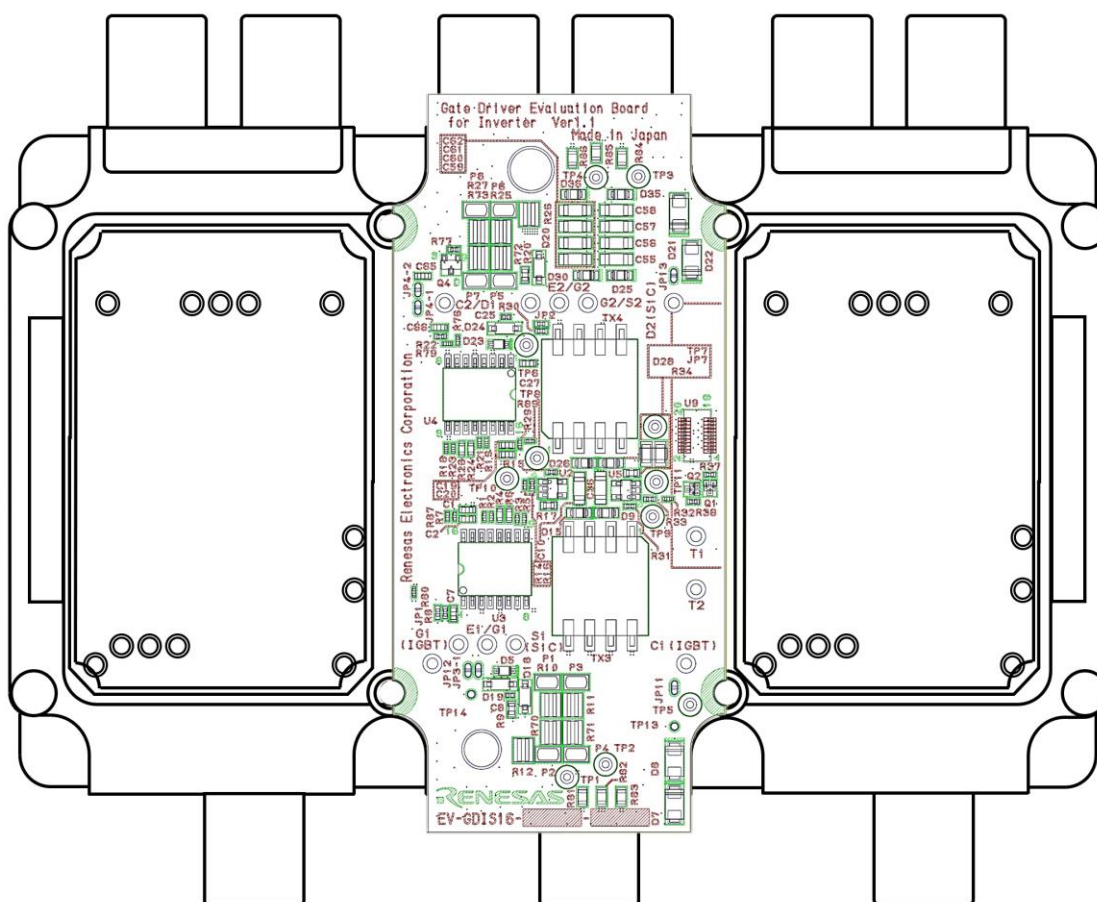


Figure 8. Image of EV-GDIS16 board with target module

Figure 3 shows the pinouts for mounting the EV-GDIS16 board on an IGBT/SiC module. The pin numbers depend on where the EV-GDIS16 board is mounted on the 6pack module.

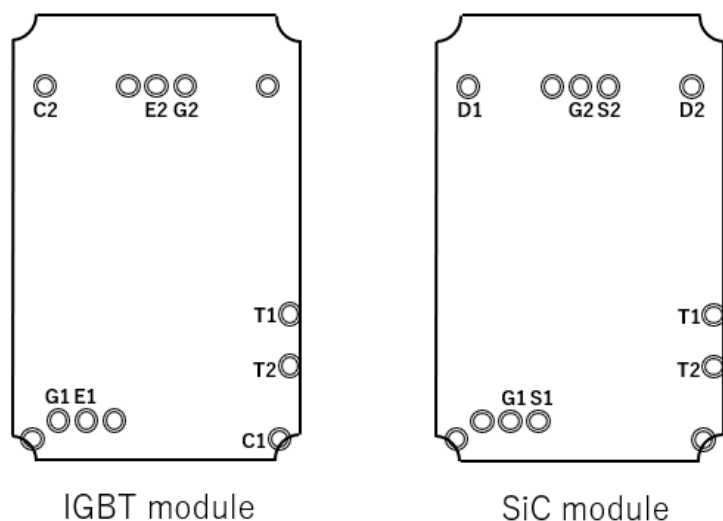


Figure 9. Connections with IGBT/SiC modules

To support both IGBT/SiC modules on a single board, the EV-GDIS16 board provides pin assignments for the target module with solder-short jumpers (Refer to Table 4).

Table 6. Solder-short jumper settings for target module

| Jumper name | For IGBT module | For SiC module |
|-------------|-----------------|----------------|
| JP3-1 | - | Short |
| JP3-2 | Short | - |
| JP4-1 | - | Short |
| JP4-2 | Short | - |
| JP5-1 | - | Short |
| JP5-2 | Short | - |
| JP6-1 | - | Short |
| JP6-2 | Short | - |
| JP11 | Short | - |
| JP12 | Short | - |
| JP13 | - | Short |
| JP14 | - | Short |

If your target IGBT/SiC module has a different pin layout than these modules, connect this board to your target module with the shortest wires.

9. EV-GDIS16 interface board

The Interface board contains easy-to-use standard pitch connectors for signal input/output to MCU board and measuring equipment. The Interface board is attached to the U9 connector on the EV-GDIS16 board. Refer to Chapter 4 for details on input/output connector U11.

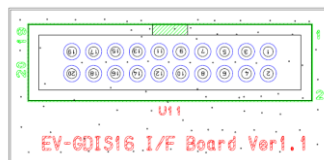


Figure 10. Interface Board

10. Optional settings

The EV-GDIS16 has an optional setting for a variety of evaluations. 0 ohm resistors and jumpers on the board can be used to change the connections to achieve the target evaluation purpose.

Table 7. Setting for target evaluation (e.g. For RAJ293000)

| Evaluation | Parts setting | Description |
|-----------------------------|---|---|
| Double Pulse Test (GDU 1pc) | (e.g. the case of IGBT) No set: R24,R84,R85,R86,JP3-2,JP9,JP10,JP11,JP12. Set: R28,R29,JP4-2,JP5-2,JP6-2 | Use only Low side. Put in R=47kohm between VCC2-GND2 & GND2-VEE of Flyback Converter is recommended. It is recommended to apply supply voltage VCC1=5V, VCC2=15V, VEE=-5V as the input voltage*, and apply pulse signal in INA. The ON & OFF times of the pulse signal are the most important points. (*When using Flyback, set R84,R85,R86 and apply VCC1=5V, VCC2(Pin 1 of U11)=12V) |
| Flyback external control | R14, R32 | This option is used to externally control the LT8301 flyback converter for U2 and U5. The EV/UVLO pin of the LT8301 on the board is always asserted by voltage divider with a resistor from +12V power supply. By mounting optional resistors R14 and R32, it is possible to control the EV/UVLO pin of the LT8301 from the 11 pin of connector U11 on the interface board. |

11. Device option

The pin assignment differs depending on the mounted Gate Driver. EV-GDIS16 is designed to allow evaluation of different pin out products with 0 ohm resistors and jumpers settings. The following 0 ohm resistors and jumpers are optional for future Gate Driver products.

Table 8. Setting for target Gate Driver device (The parts in parentheses are low side parts)

| Parts No. | RAJ293000 |
|-----------|-----------|
| R4 (R24) | Mount |
| R5 (R18) | - |
| JP1 (JP2) | - |
| R7 (R29) | - |
| R81~R86 | Mount |
| R87 (R89) | - |
| R88 (R90) | - |
| R91 (R92) | - |
| R93 | - |
| R74 (R76) | - |
| R75 (R77) | - |
| Q3 (Q4) | - |

12. Schematics

The EV-GDIS16 board schematic is shown below.

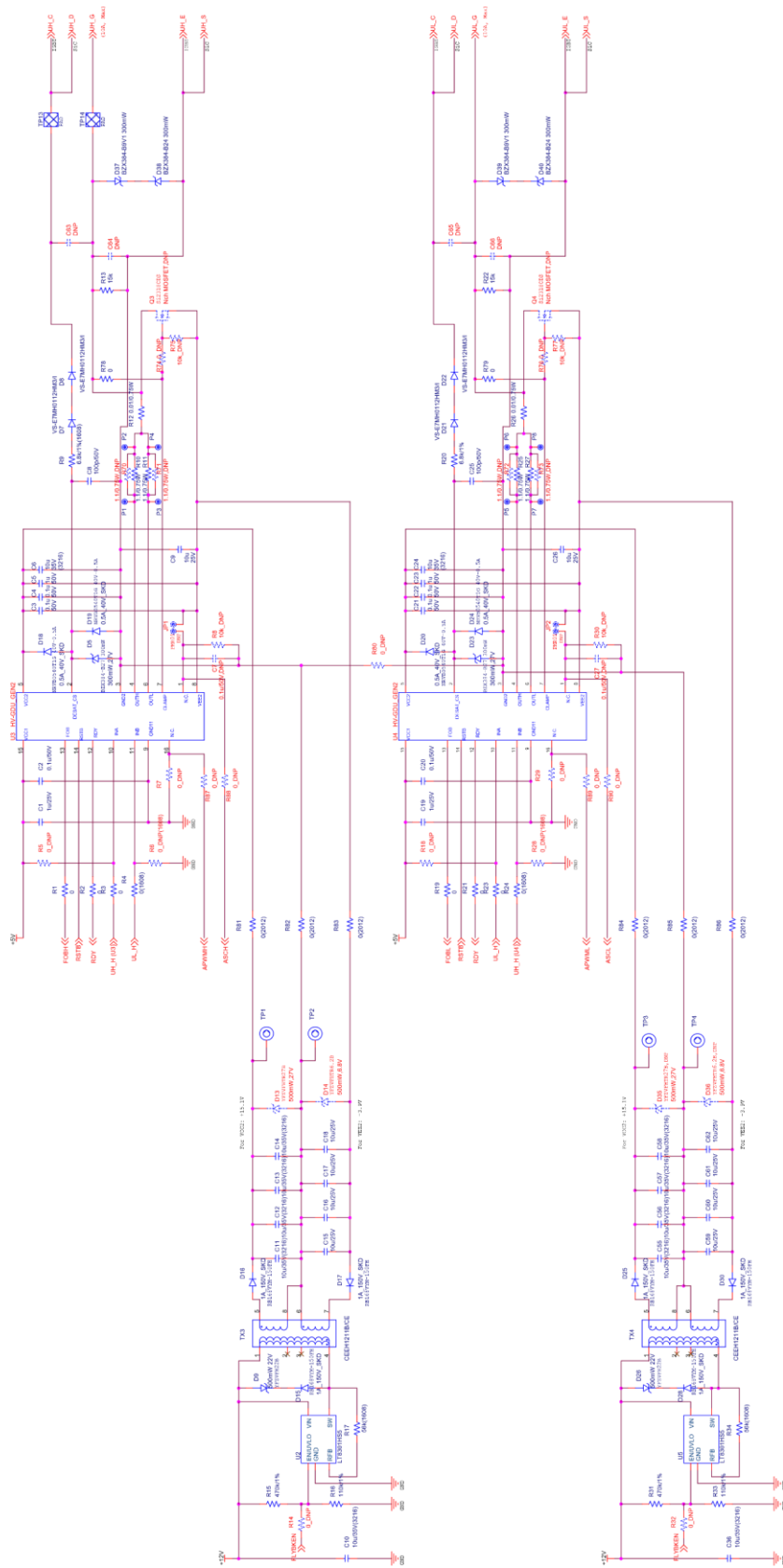


Figure 11. EV-GDIS16 schematics - Gate Driver IC and flyback

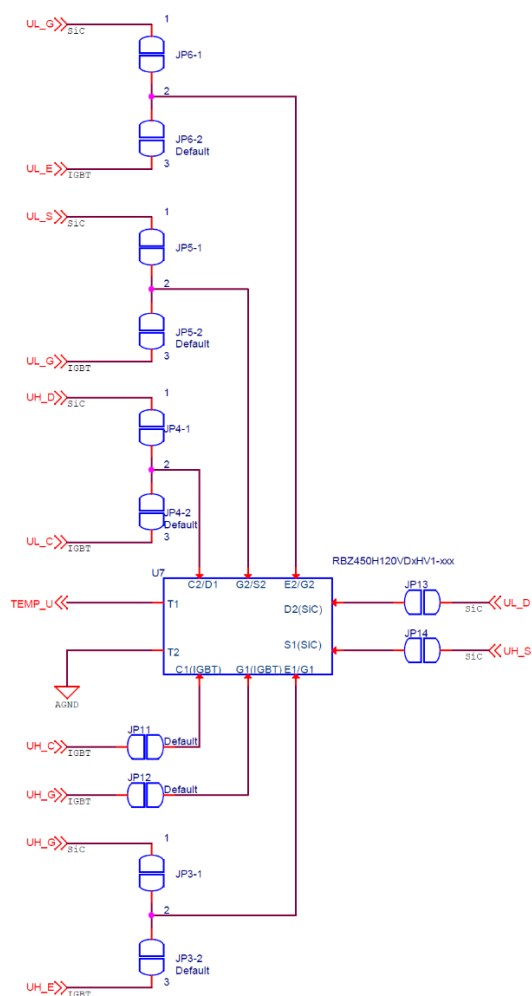


Figure 12. EV-GDIS16 schematics – IGBT/SiC module interface.

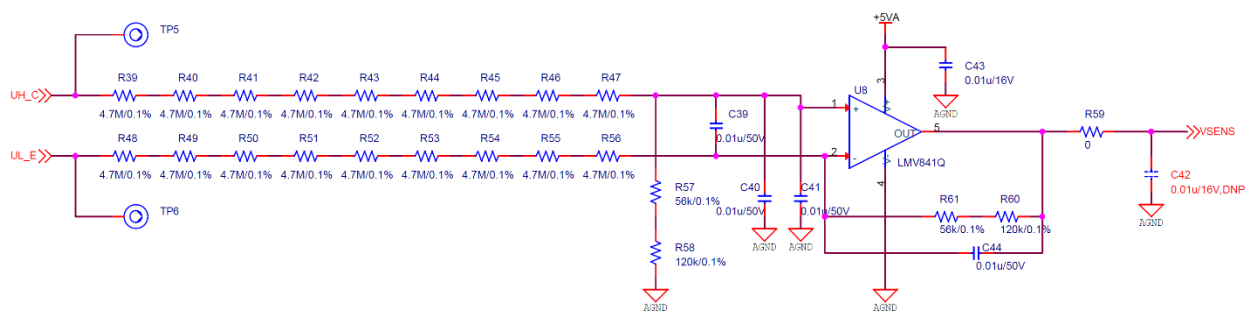


Figure 13. EV-GDIS16 schematics - VSENS

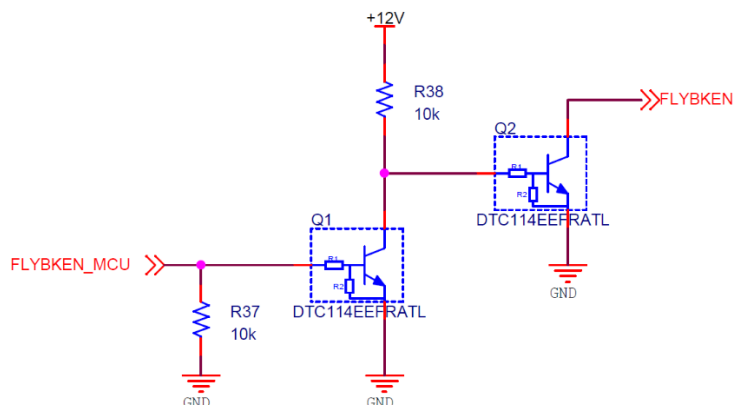


Figure 14. EV-GDIS16 schematics – FLYBACK voltage conversion

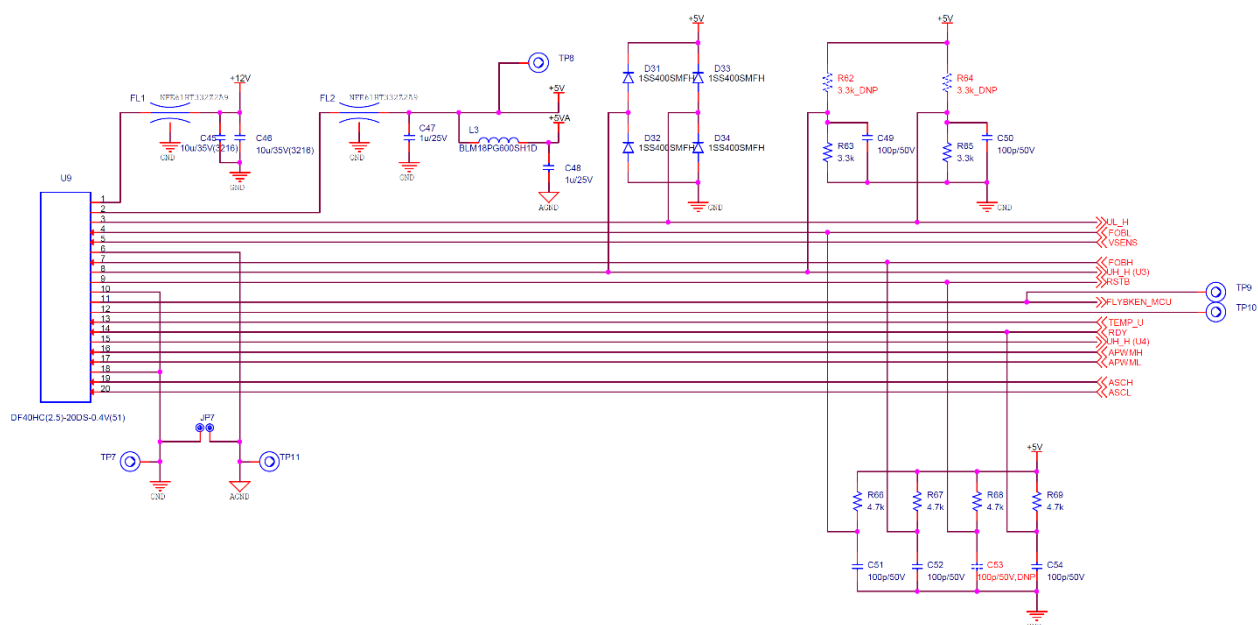


Figure 15. EV-GDIS16 schematics – Interface and power

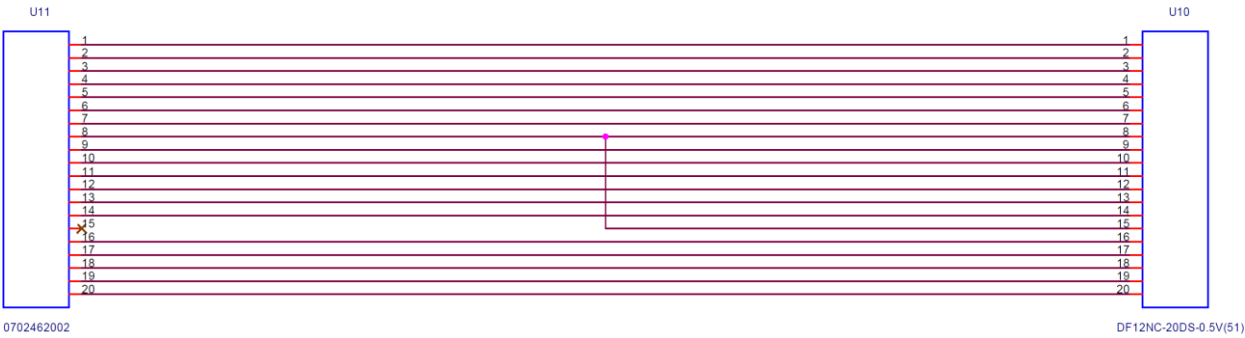


Figure 16. EV-GDIS16 schematics – Interface Board

13. Parts list

The following is a list of the components mounted on the EV-GDIS16. Some of the mounted components have lower heat resistance than the operating temperature range of Gate Driver. If evaluated in high temperature, remove the parts as necessary.

Table 9. EV-GDIS16 parts list - 1/4

| Symbol | Parts name | Part number | Vendor | Note |
|--------------------|-------------------|---------------------------|-----------------------|------|
| U3, U4 | Gate Driver IC | RAJ293000/SO_1 | Renesas | |
| U2, U5 | Flyback converter | LT8301JS5#WTRMPBF | Linear Technology | |
| U8 | Op-Amp | LMV841Q | Texas Instruments | |
| U9 | Connector | DF12NC(3.5)-20DP-0.5V(51) | Hirose | |
| TX3 | Trans | CEEH1211B/CE | Sumida | |
| TX4 | Trans | CEEH1211B/CE | Sumida | |
| FL1, FL2 | NFE61HT332Z2A9 | NFE61HT332Z2A9L | Murata | |
| Q1, Q2 | DTC114EEFRA | DTC114EEFRATL | ROHM | |
| Q3, Q4 | Si2318CDS, N/A | Si2318CDS-T1-GE3 | VISHAY | |
| L3 | BLM18PG600SH1D | BLM18PG600SH1D | Murata | |
| D5 | BZX384-B27 300mV | BZX384-B27,115 | Nexperia | |
| D7, D8 | VS-E7MH0112HM3/I | VS-E7MH0112HM3/I | Vishay Semiconductors | |
| D9 | YFZVFH22B | YFZVFHTR22B | ROHM | |
| D13 | YFZVFHTR27B N/A | YFZVFHTR27B | ROHM | |
| D14 | YFZVFHTR6.2B N/A | YFZVFHTR6.2B | ROHM | |
| D15, D16, D17 | RB168VYM-150FH | RB168VYM150FHTR | ROHM | |
| D18, D19 | STPS0540Z | STPS0540Z | ST Micro | |
| D20, D24 | STPS0540Z | STPS0540Z | ST Micro | |
| D21, D22 | VS-E7MH0112HM3/I | VS-E7MH0112HM3/I | Vishay Semiconductors | |
| D23 | BZX384-B27 300mV | BZX384-B27,115 | Nexperia | |
| D25, D28, D30 | RB168VYM-150FH | RB168VYM150FHTR | ROHM | |
| D26 | YFZVFH22B | YFZVFHTR22B | ROHM | |
| D31, D32, D33, D34 | 1SS400SMFH | 1SS400SMFHT2R | ROHM | |
| D35 | YFZVFHTR27B N/A | YFZVFHTR27B | ROHM | |
| D36 | YFZVFHTR6.2B N/A | YFZVFHTR6.2B | ROHM | |
| D37 | BZX384-B9V1 300mW | BZX384-B9V1,115 | Nexperia | |

Table 10. EV-GDIS16 parts list - 2/4

| Symbol | Parts name | Part number | Vendor | Note |
|---|---------------------|--------------------------|-----------|------|
| D38 | BZX384-B24 300mW | BZX384-B24,115 | Nexperia | |
| D39 | BZX384-B9V1 300mW | BZX384-B9V1,115 | Nexperia | |
| D40 | BZX384-B24 300mW | BZX384-B24,115 | Nexperia | |
| P1, P2, P3, P4, P5, P6, P7, P8 | Test pin | PE-1 | MAC8 | |
| JP1 | PMR01 N/A | PMR01ZZPJ000 | ROHM | |
| JP2 | PMR01 N/A | PMR01ZZPJ000 | ROHM | |
| JP3-1, JP3-2, JP4-1, JP4-2, JP5-1, JP5-2, JP6-1, JP6-2, JP11, JP12, JP13, JP14 | Solder short jumper | - | - | |
| JP7 | Jumper | HWC-2P-G | MAC8 | |
| TP1, TP2, TP13, TP14 | Test Pin | (ϕ 1mm round hole) | - | |
| TP3, TP4 | Test Pin | (ϕ 1mm round hole) | - | |
| TP5, TP6, TP7, TP8, TP9, TP10, TP11 | Test Pin | (ϕ 1mm round hole) | - | |
| R1, R2, R3, R78 | 0 | RK73Z1ERTTP | KOA | |
| R10, R11 | 1.1/0.75W | ERJ-B2BF1R1V | Panasonic | |
| R12 | 0.01/0.75W | ERJ-B2CFR01V | Panasonic | |
| R13 | 15k | ERJ-2GEJ153X | Panasonic | |
| R15 | 470k/1% | ERJ-2RKF4703X | Panasonic | |
| R16 | 110k/1% | ERJ-2RKF1103X | Panasonic | |
| R17 | IGBT/SiC:56k/1% | ERJ-3EKF5602V | Panasonic | |
| R18, R29, R32, R76, R89, R90 | 0 N/A | RK73Z1ERTTP | KOA | |
| R19, R21, R23, R79 | 0 | RK73Z1ERTTP | KOA | |
| R20 | 6.8k/1% | ERJ-3EKF6801V | Panasonic | |
| R22 | 15k | ERJ-2GEJ153X | Panasonic | |
| R25, R27 | 1.1/0.75W | ERJ-B2BF1R1V | Panasonic | |

Table 11. EV-GDIS16 parts list - 3/4

| Symbol | Parts name | Part number | Vendor | Note |
|--|-----------------|--------------------|-----------|------|
| R26 | 0.01/0.75W | ERJ-B2CFR01V | Panasonic | |
| R30, R77 | 10kN/A | ERJ-2GEJ103X | Panasonic | |
| R31 | 470k/1% | ERJ-2RKF4703X | Panasonic | |
| R33 | 110k/1% | ERJ-2RKF1103X | Panasonic | |
| R34 | IGBT/SiC:56k/1% | ERJ-3EKF5602V | Panasonic | |
| R37, R38 | 10k | ERJ-2GEJ103X | Panasonic | |
| R39, R40, R41, R42, R43, R44, R45, R46, R47, R48, R49, R50, R51, R52, R53, R54, R55, R56 | 4.7M/0.1% | MCA1206MD4704BP100 | Vishay | |
| R5, R7, R14, R74, R78, R87, R88 | 0 N/A | RK73Z1ERTTP | KOA | |
| R4, R6, R24, R28 | 0 | RK73Z1JTDD | KOA | |
| R57, R61 | 56k/0.1% | ERA-3AEB563V | Panasonic | |
| R58, R60 | 120k/0.1% | ERA-3AEB124V | Panasonic | |
| R59 | 0 | RK73Z1ERTTP | KOA | |
| R62, R64 | 3.3k N/A | ERJ-2GEJ332X | Panasonic | |
| R63, R65 | 3.3k | ERJ-2GEJ332X | Panasonic | |
| R66, R67, R68, R69 | 4.7k | ERJ-2GEJ472X | Panasonic | |
| R70, R71 | 1.1/0.75W N/A | ERJ-B2BF1R1V | Panasonic | |
| R72, R73 | 1.1/0.75W N/A | ERJ-B2BF1R1V | Panasonic | |
| R8, R75 | 10kN/A | ERJ-2GEJ103X | Panasonic | |
| R80 | 0 N/A | RK73Z1ERTTP | KOA | |
| R81, R82, R83 | 0 | RK73Z2ATTD | KOA | |
| R84, R85, R86 | 0 | RK73Z2ATTD | KOA | |
| R9 | 6.8k/1% | ERJ-3EKF6801V | Panasonic | |

Table 12. EV-GDIS16 parts list - 4/4

| Symbol | Parts name | Part number | Vendor | Note |
|------------------------------|-----------------|------------------------|--------|------|
| C1 | 1uF/25V | CGA3E1X7R1E105K080AC | TDK | |
| C2, C3, C4 | 0.1uF/50V | CGA3E2X7R1H104K080AA | TDK | |
| C5 | 1uF/50V | CGA4J3X7R1H105K125AB | TDK | |
| C6, C10, C11, C12, C13, C14 | 10uF/35V(3216) | CGA5L1X7R1V106M160AE | TDK | |
| C7 | 0.1uF/50VN/A | CGA3E2X7R1H104K080AA | TDK | |
| C8 | 100pF/50V | CGA2B2C0G1H101J050BA | TDK | |
| C9, C15, C16, C17, C18 | 10uF/25V | CGA5L1X7R1E106K160AC | TDK | |
| C19 | 1uF/25V | CGA3E1X7R1E105K080AC | TDK | |
| C20, C21, C22 | 0.1uF/50V | CGA3E2X7R1H104K080AA | TDK | |
| C23 | 1uF/50V | CGA4J3X7R1H105K125AB | TDK | |
| C24, C36, C55, C56, C57, C58 | 10uF/35V(3216) | CGA5L1X7R1V106M160AE | TDK | |
| C25 | 100pF/50V | CGA2B2C0G1H101J050BA | TDK | |
| C26, C59, C60, C61, C62 | 10uF/25V | CGA5L1X7R1E106K160AC | TDK | |
| C27 | 0.1uF/50VN/A | CGA3E2X7R1H104K080AA | TDK | |
| C39, C40, C41, C44 | 0.01uF/50V | CGA2B3X7R1H103K050BB | TDK | |
| C42 | 0.01uF/16V N/A | C0805C103J4RECAUTO7210 | KEMET | |
| C43 | 0.1uF/16V | CGA2B1X7R1C104K050BC | TDK | |
| C45, C46 | 10uF/35V (3216) | CGA5L1X7R1V106M160AE | TDK | |
| C47, C48 | 1uF/25V | CGA3E1X7R1E105K080AC | TDK | |
| C49, C50, C51, C52, C54 | 100pF/50V | CGA2B2C0G1H101J050BA | TDK | |
| C53 | 100pF/50V(N/A) | CGA2B2C0G1H101J050BA | TDK | |
| C63, C64 | N/A | - | - | |
| C65, C66 | N/A | - | - | |

14. Reference document

For the specifications of the Gate Driver ICs supported by the EV-GDIS16 board, please refer to the following datasheet.

Table 13. Gate Driver datasheets

| | |
|-------------|---------------------------|
| Part number | Datasheet document number |
| RAJ293000 | R33DS0037EJ |

Revision History

| Rev. | Date | Description | |
|------|---------------|-------------|------------------------|
| | | Page | Summary |
| 1.00 | Feb. 08, 2024 | - | First official release |
| 1.01 | May 12, 2025 | 5,9 | Description revised |

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